ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND V+0.3V to +13.0V V13.0V to +0.3V	Continuous Power Dissipation (T _A = +70°C) (Note 2) Plastic DIP (derate 10.53mW/°C above +70°C)842mW Narrow SO (derate 8.70mW/°C above +70°C)696mW
V+ to V0.3V to +13.0V	QSOP (derate 8.00mW/°C above +70°C)800mW
All Other Pins (Note 1)(V0.3V) to (V+ + 0.3V)	Operating Temperature Ranges
Continuous Current into Any Terminal±10mA	MAX453_C_ E0°C to +70°C
Peak Current into Any Terminal	MAX453_E_ E40°C to +85°C
(pulsed at 1ms,10% duty cycle)±20mA	Storage Temperature Range65°C to +150°C
ESD per Method 3015.7>2000V	Lead Temperature (soldering, 10sec)+300°C

- Note 1: Signals on NC_, NO_, COM_, EN, or IN_ exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.
- Note 2: All leads are soldered or welded to PC boards.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—±5V Dual Supplies

(V+ = 4.5V to 5.5V, V- = -4.5V to -5.5V, V_{INH} = 2.4V, V_{INL} = 0.8V, $V_{\overline{EN}}$ = 0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
ANALOG SWITCH							1
Analog Signal Range	V _{COM_} ,	(Note 4)	C, E	V-		V+	V
COM_ NO_, COM_ NC_	RON	V+ = 4.5V, V- = -4.5V,	+25°C		55	100	Ω
On-Resistance	NON	V _{COM} _ = 3.5V, I _{COM} _ = 1mA	C, E			125	32
COM_ NO_, COM_ NC_ On-Resistance Match Between	ΔRON	V+ = 4.5V, V- = -4.5V,	+25°C		1	4	Ω
Channels (Note 5)	AIXON	V _{COM} _ = 3.5V, I _{COM} _ = 1mA	C, E			6	
COM_ NO_, COM_ NC_	RFLAT(ON)	V+ = 5.0V, V- = -5.0V,			4	10	Ω
On-Resistance Flatness (Note 6)	TYFLAT(ON)	$V_{COM} = -3.0V, 0, +3.0V, I_{COM} = 1mA$	C, E			15	22
NO_, NC_ Off-Leakage Current	INO_(OFF),	V+ = 5.5V, V- = -5.5V,	+25°C	-1	0.01	1	nA
(Note 7)	INC_(OFF)	$V_{COM} = \pm 4.5V, V_{N} = \mp 4.5V$	C, E	-10		10	11/ (
COM_ Off-Leakage Current	I _{COM_(OFF)}	V+ = 5.5V, V- = -5.5V,	+25°C	-1	0.01	1	nA
(Note 7)	'COIVI_(OFF)	$V_{COM} = \pm 4.5V, V_{N} = \mp 4.5V$	C, E	-10		10	117 (
COM_ On-Leakage Current	ICOM_(ON)	V+ = 5.5V, V- = -5.5V,	+25°C	-2	0.01	2	nA
(Note 7)	ICONI_(ON)	$V_{COM} = \pm 4.5V, V_{N} = \pm 4.5V$ C, E -2	-20		20	11/3	
LOGIC INPUT							
EN, IN_ Input Logic Threshold High	V _{INH}		C, E		1.4	2.4	V
EN, IN_ Input Logic Threshold Low	V _{INL}		C, E	0.8	1.4		V
EN, IN_ Input Current Logic High or Low	I _{NH} _, I _{INL} _	V _{IN} _ = 0.8V or 2.4V	C, E	-1	0.03	1	μА

ELECTRICAL CHARACTERISTICS—±5V Dual Supplies (continued)

(V+ = 4.5V to 5.5V, V- = -4.5V to -5.5V, V_{INH} = 2.4V, V_{INL} = 0.8V, $V_{\overline{EN}}$ = 0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
SWITCH DYNAMIC CHARACTERI	STICS						
Turn-On Time	ton	$V_{COM} = \pm 3V, V_{+} = 4.5V,$	+25°C		35	100	ns
Turr-On Time	ton	V = -4.5V (Figure 1)	C, E			125	1115
Turn-Off Time	toff	$V_{COM} = \pm 3V, V_{+} = 4.5V,$	+25°C		15	50	ns
rum-on nine	IOFF	V- = -4.5V (Figure 1)	C, E			60	113
Break-Before-Make Time Delay (MAX4538 Only)	t _{BBM}	V _{COM} = ±3V, V+ = 5.5V, V- = -5.5V (Figure 2)	+25°C	5	15		ns
Charge Injection (Figure 3)	Q	$C_L = 1.0 nF, V_{NO} = 0 V, R_S = 0 \Omega$	+25°C		1	5	рС
NO_, NC_ Off-Capacitance (Figure 6)	C _{N_(OFF)}	V _{NO} _ = GND, f = 1MHz	+25°C		2		pF
COM_ Off-Capacitance (Figure 6)	C _{COM_(OFF)}	V _{COM} _ = GND, f = 1MHz	+25°C		2		pF
COM_ On-Capacitance (Figure 7)	CCOM_(ON)	V _{COM} _ = V _{NO} _ = GND, f = 1MHz	+25°C		6		pF
Off-Isolation (Note 8, Figure 4)	V _{ISO}	$R_L = 50\Omega$, $C_L = 15pF$, $V_{N} = 1V_{RMS}$, $f = 1MHz$	+25°C		-65		dB
Channel-to-Channel Crosstalk (Note 9, Figure 5)	V _{CT}	$R_L = 50\Omega$, $C_L = 15pF$, $V_{N} = 1V_{RMS}$, $f = 1MHz$	+25°C		-75		dB
POWER SUPPLY							
Power-Supply Range	V+, V-		C, E	-6		6	V
V+ Supply Current	I+	V+ = 5.5V, all V _{IN} _ = 0V or V+	+25°C	-1	0.05	1	
			C, E	-10		10	- μΑ
V- Supply Current	-	V- = -5.5V	+25°C	-1	0.05	1	μΑ
v- Supply Current	'		C, E	-10		10	μΑ

ELECTRICAL CHARACTERISTICS—+5V Single Supply

(V+ = 4.5V to 5.5V, V- = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V, $V_{\overline{EN}}$ = 0.8V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
ANALOG SWITCH							II.
Analog Signal Range	V _{COM_} , V _{NO_} , V _{NC}	(Note 4)	C, E	0		V+	V
COMNO_, COMNC_	R _{ON}	V+ = 4.5V, V _{COM} _ = 3.5V,	+25°C		90	200	Ω
On-Resistance	NON	I _{COM} _ = 1mA	C, E			225	
COMNO_, COMNC_ On-Resistance Match Between	ΔR_ON	$V + = 4.5V, V_{COM} = 3.5V,$	+25°C		2	8	Ω
Channels (Note 5)		I _{COM} = 1mA	C, E			10	
NO_, NC_ Off-Leakage Current	I _{NO_(OFF),}	V+ = 5.5V, V _{COM} _ = 1V, 4.5V,	+25°C	-1	0.01	1	nA
(Notes 7, 10)	INC_(OFF)	$V_{N_{-}} = +4.5V, 1V$	C, E	-10		10	
COM_ Off-Leakage Current	loou (055)	V+ = 5.5V, V _{COM} _ = 1V, 4.5V,	+25°C	-1	0.01	1	nΛ
(Notes 7, 10)	ICOM_(OFF)	V _N _ = +4.5V, 1V	C, E	-10		10	nA
COM_ On-Leakage Current	1	OM_(ON) V+ = 5.5V, V _{COM} _ = 1V, 4.5V,	+25°C	-2	0.01	2	nA
(Note 7, 10)	ICOM_(ON)		C, E	-20		20	
LOGIC INPUT							<u> </u>
EN, IN_ Input Logic Threshold High	V _{INH}		C, E		1.4	2.4	V
EN, IN_ Input Logic Threshold Low	V _{INL}		C, E	0.8	1.4		V
EN, IN_ Input Current Logic High or Low	I _{INH_} , I _{INL_}	V _{IN} _ = 0.8V or 2.4V	C, E	-1	0.03	1	μA
SWITCH DYNAMIC CHARACTERIS	STICS		-1				- 11:
Turn-On Time	1	V _{COM} _ = 3V, V+ = 4.5V (Figure 1)	+25°C		50	100	ns
Turri-Ori Time	ton		C, E		20	125	
Turn-Off Time	torr	$V_{COM} = 3V, V_{+} = 4.5V$	+25°C			80	
Turri-Oir Time	toff	(Figure 1)	C, E			100	– ns
Break-Before-Make Time Delay	t _{BBM}	MAX4538, V _{COM} = 3V, V+ = 5.5V (Figure 2)	+25°C	5	25		ns
Charge Injection (Figure 3) (Note 4)	Q	$C_L = 1.0$ nF, $V_{NO} = 0$ V, $R_S = 0$ Ω	+25°C		1	5	рС
POWER SUPPLY			1				1
V. Supply Current	Li	V+ = 5.5V, all V _{IN} _ = 0V or V+	+25°C	-1	0.05	1	
V+ Supply Current	I+		C, E	-10		10	μA

ELECTRICAL CHARACTERISTICS—+3V Single Supply

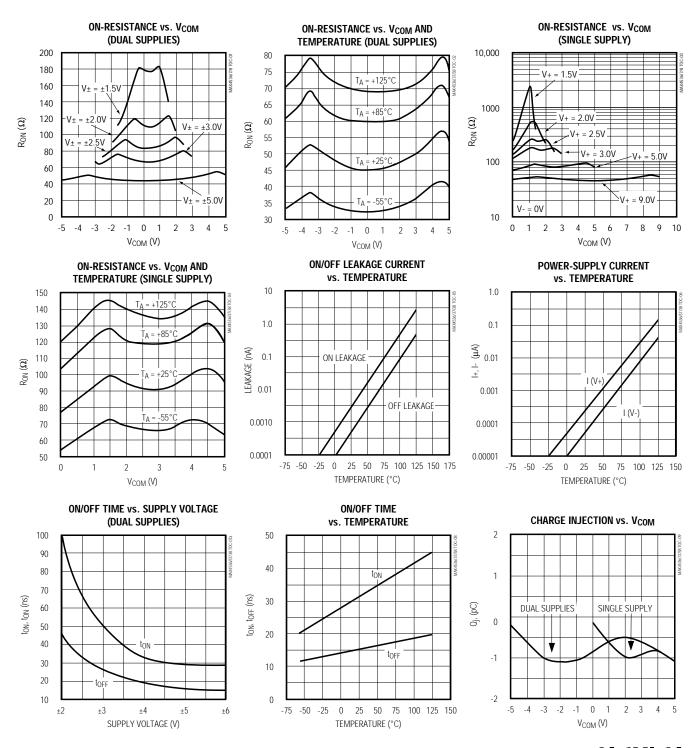
(V+ = 2.7V to 3.6V, V- = 0V, V_{INH} = 2.0V, V_{INL} = 0.5V, $V_{\overline{EN}}$ = 0.5V, T_A = T_{MIN} to T_{MAX} , unless otherwise noted. Typical values are at T_A = +25°C.)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP (Note 3)	MAX	UNITS
ANALOG SWITCH							
Analog Signal Range	V _{COM_} , V _{NO_} , V _{NC}	(Note 4)	C, E	0		V+	V
COMNO_, COMNC_	Ron	V+ = 2.7V, V _{COM} _ = 1.5V,	+25°C		210	500	Ω
On-Resistance	NON	I _{COM} _ = 0.1mA	C, E			600	
LOGIC INPUT							
EN, IN_ Input Logic Threshold High	VINH		C, E		0.9	2.0	V
EN, IN_ Input Logic Threshold Low	V _{INL}		C, E	0.5	0.9		V
EN, IN_ Input Current Logic High or Low	I _{INH} _, I _{INL} _	V _{IN} _ = 0.8V or 2.4V	C, E	-1	0.03	1	μА
SWITCH DYNAMIC CHARACTERIS	STICS (Note 4	1)					
Turn-On Time	ton	V _{COM} _ = 1.5V, V+ = 2.7V (Figure 1)	+25°C		80	250	nc
Turn-On Time			C, E			300	ns
Turn-Off Time	1	$V_{COM} = 1.5V, V_{+} = 2.7V$	+25°C		40	100	
Turn-Oil Time	toff	(Figure 1)	C, E			120	ns
Break-Before-Make Time Delay	tввм	MAX4538, V _{COM} = 1.5V, V+ = 3.6V (Figure 2)	+25°C	10	40		ns
Charge Injection (Figure 3)	Q	$C_L = 1.0$ nF, $V_{NO} = 0$ V, $R_S = 0$ Ω	+25°C			3	рС
POWER SUPPLY			•				
V. Supply Current	l+	V+ = 3.6V, all V _{IN} _ = 0V or V+	+25°C	-1	0.05	1	
V+ Supply Current			C, E	-10		10	μA

- **Note 3:** The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
- Note 4: Guaranteed by design.
- **Note 5:** $\Delta R_{ON} = \Delta R_{ON(MAX)} \Delta R_{ON(MIN)}$.
- **Note 6:** Resistance flatness is defined as the difference between the maximum and the minimum value of on-resistance as measured over the specified analog-signal range.
- **Note 7:** Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at $T_A = +25$ °C.
- Note 8: Off-isolation = $20log_{10} [V_{COM} / (V_{NC} \text{ or } V_{NO})]$, $V_{COM} = \text{ output}$, $V_{NC} \text{ or } V_{NO} = \text{ input to off switch.}$
- Note 9: Between any two switches.
- Note 10: Leakage testing for single-supply operation is guaranteed by testing with dual supplies.

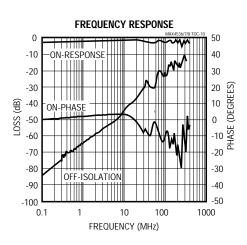
Typical Operating Characteristics

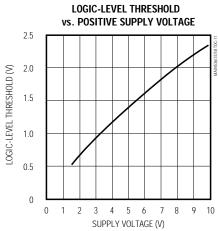
 $(V + = +5V, V - = -5V \text{ GND} = 0V, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$

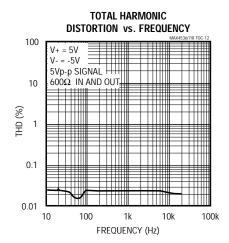


Typical Operating Characteristics (continued)

 $(V + = +5V, V - = -5V \text{ GND} = 0V, T_A = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$







Pin Description

PIN	NAME	FUNCTION
1, 4, 10, 13	COM1-COM4	Analog Switch Common* Terminals
2, 3, 11, 12	NO1–NO4, or NC1–NC4	Analog Switch Normally Open* or Normally Closed* Terminals (see <i>Truth Tables</i>)
5, 6, 14, 15	IN1-IN4	Logic-Control Digital Inputs. Control each switch (see <i>Truth Tables</i>), except when EN is high.
7	EN	Disable Logic Input. Connect logic high to EN to disable (open) all switches.
8	GND	Ground. Connect to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
9	V-	Negative Analog Supply-Voltage Input. Connect V- to GND for single-supply operation.
16	V+	Positive Analog and Digital Supply-Voltage Input. Internally connected to substrate.

^{*}NO_/NC_ and COM_ pins are identical and interchangeable. Either may be considered as an input or an output; signals pass equally well in either direction.

_Applications Information

Power-Supply Considerations

Overview

The MAX4536/MAX4537/MAX4538 construction is typical of most CMOS analog switches. These devices have three supply pins: V+, V-, and GND. V+ and V- drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog-signal pin, and both V+ and V-. One of these diodes conducts if any analog signal exceeds V+ or V-. These reverse-biased ESD diodes leak during normal operation, forming the only current drawn from V+ or V-.

Virtually all the analog leakage current is through the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages vary as the signal varies. The *difference* in the two diode leakages from the signal path to the V+ and V- pins constitutes the analog-signal path leakage current. All analog leakage current flows to the supply terminals, not to the other switch terminal. This explains how both sides of a given switch can show leakage currents of either the same or opposite polarity.

There is no connection between the analog-signal paths and GND. The analog-signal paths consist of an N-channel and P-channel MOSFET with their sources and drains paralleled and their gates driven out of phase to V+ and V- by the logic-level translators.

V+ and GND power the internal logic and logic-level translators and set the input logic thresholds. The logic-level translators convert the logic levels to switched V+ and V- signals to drive the analog switches' gates. This drive signal is the only connection between the logic supplies and the analog supplies. V+, and V- have ESD-protection diodes to GND. The logic-level inputs have ESD protection to V+ and to V-

Increasing V- has no effect on the logic-level thresholds, but it does increase the drive to the P-channel switches, reducing their on-resistance. V- also sets the negative limit of the analog-signal voltage.

The logic-level thresholds are CMOS/TTL-compatible when V+ is +5V. The threshold increases slightly as V+ is raised. When V+ reaches +12V, the level threshold is about 3.1V, above the TTL output high-level minimum of 2.8V, but still compatible with CMOS outputs.

Bipolar Supplies

The MAX4536/MAX4537/MAX4538 operate with bipolar supplies between ±2.0V and ±6V. The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the absolute maximum rating of 13.0V. Do not connect the MAX4536/MAX4537/MAX4538's V+ to +3V and then connect the logic-level input pins to TTL logic-level signals. TTL logic-level outputs in excess of the absolute maximum ratings can damage the part and/or external circuits.

CAUTION: The absolute maximum V+ to V- differential voltage is 13.0V. Typical ±6V or +12V supplies with ±10% tolerances can be as high as 13.2V. This voltage can damage the MAX4536/MAX4537/MAX4538. Even ±5% tolerance supplies may have overshoot or noise spikes that exceed 13.0V.

Single Supplies

The MAX4536/MAX4537/MAX4538 operate from single supplies between +2.0V and +12V when V- is connected to GND. All of the bipolar precautions must be observed.

High-Frequency Performance

In 50Ω systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on-response has several minor peaks that are highly layout dependent. The problem with high-frequency operation is not in turning the switch on, but in turning it off. The off-state switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off-isolation is about -44dB in 50Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also make off-isolation worse. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is due entirely to capacitive coupling.

Test Circuits/Timing Diagrams

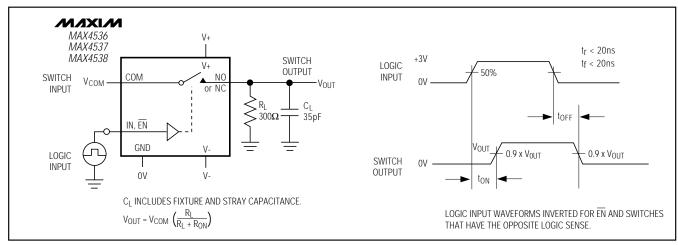


Figure 1. Switching Time

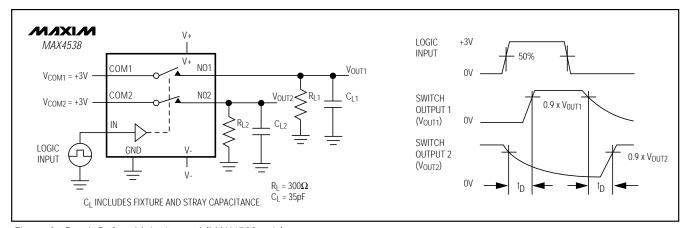


Figure 2. Break-Before-Make Interval (MAX4538 only)

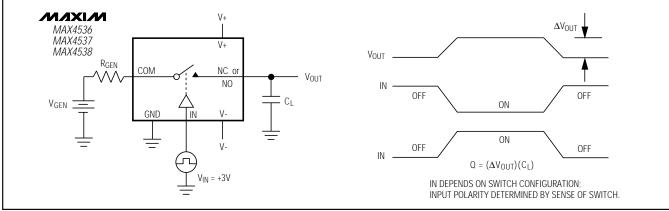


Figure 3. Charge Injection

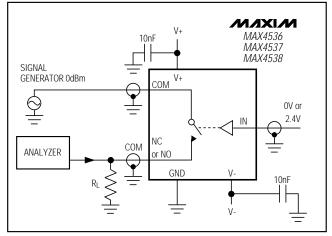


Figure 4. Off Isolation

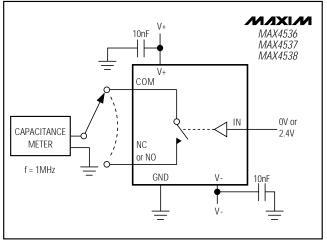


Figure 6. Channel-Off Capacitance

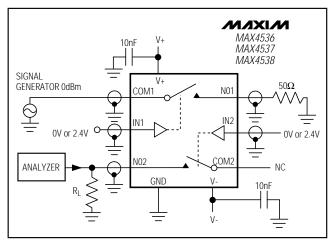


Figure 5. Crosstalk

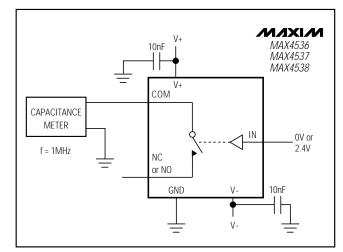


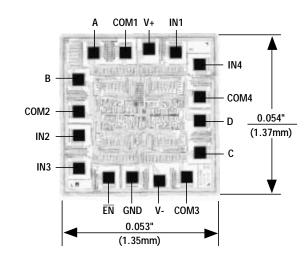
Figure 7. Channel-On Capacitance

_Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX4537CPE	0°C to +70°C	16 Plastic DIP
MAX4537CSE	0°C to +70°C	16 Narrow SO
MAX4537CEE	0°C to +70°C	16 QSOP
MAX4537C/D	0°C to +70°C	Dice*
MAX4537EPE	-40°C to +85°C	16 Plastic DIP
MAX4537ESE	-40°C to +85°C	16 Narrow SO
MAX4537EEE	-40°C to +85°C	16 QSOP
MAX4538CPE	0°C to +70°C	16 Plastic DIP
MAX4538CSE	0°C to +70°C	16 Narrow SO
MAX4538CEE	0°C to +70°C	16 QSOP
MAX4538C/D	0°C to +70°C	Dice*
MAX4538EPE	-40°C to +85°C	16 Plastic DIP
MAX4538ESE	-40°C to +85°C	16 Narrow SO
MAX4538EEE	-40°C to +85°C	16 QSOP

^{*}Contact factory for availability.

_Chip Topography

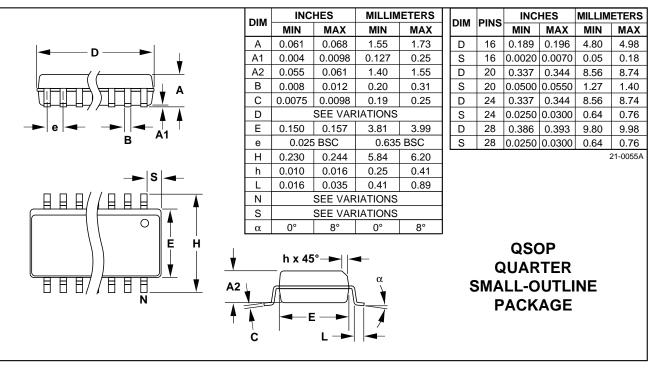


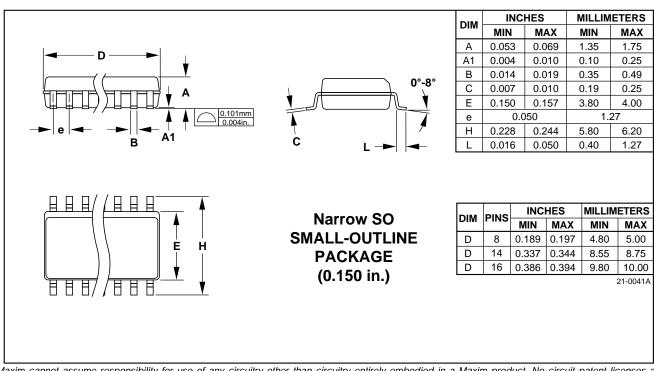
MAX	4536	MAX	MAX4537 MAX453		MAX4537		4538
PIN	NAME	PIN	NAME	PIN	NAME		
А	NO1	А	NC1	А	NO1		
В	NO2	В	NC2	В	NC2		
С	NO3	С	NC3	С	NC3		
D	NO4	D	NC4	D	NO4		

TRANSISTOR COUNT: 121

SUBSTRATE IS INTERNALLY CONNECTED TO V+

Package Information





Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time.

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